

**Vishay Semiconductors** 

# Small Signal Fast Switching Diode

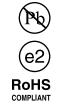


### FEATURES

- Silicon epitaxial planar diodes
- Electrical data identical with the device 1N4154
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

## APPLICATIONS

• Extreme fast switches



# **ADDITIONAL RESOURCES**



#### **MECHANICAL DATA**

Case: MiniMELF (SOD-80) Weight: approx. 31 mg Cathode band color: black Packaging codes / options:

GS18/10K per 13" reel (8 mm tape), 10K/box GS08/2.5K per 7" reel (8 mm tape), 12.5/K box

| PARTS TABLE |                            |   |        |               |  |  |
|-------------|----------------------------|---|--------|---------------|--|--|
| PART        | ORDERING CODE              | ORDERING CODE TYPE MARKING CIRCUIT CONFIGURATION RE |        | REMARKS       |  |  |
| LL4154      | LL4154-GS18 or LL4154-GS08 | -   | Single | Tape and reel |  |  |

| ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified) |                       |                    |       |      |  |
|---|-----------------------|--------------------|-------|------|--|
| PARAMETER   | TEST CONDITION        | SYMBOL             | VALUE | UNIT |  |
| Repetitive peak reverse voltage   |                       | V <sub>RRM</sub>   | 35    | V    |  |
| Reverse voltage   |                       | V <sub>R</sub>     | 25    | V    |  |
| Peak forward surge current  | t <sub>p</sub> = 1 μs | I <sub>FSM</sub>   | 2     | А    |  |
| Repetitive peak forward current   |                       | I <sub>FRM</sub>   | 500   | mA   |  |
| Forward continuous current  |                       | I <sub>F</sub>     | 300   | mA   |  |
| Average forward current   | V <sub>R</sub> = 0    | I <sub>F(AV)</sub> | 150   | mA   |  |
| Power dissipation   |                       | P <sub>tot</sub>   | 500   | mW   |  |

| <b>THERMAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |                                       |                   |             |      |  |
|---|---------------------------------------|-------------------|-------------|------|--|
| PARAMETER   | TEST CONDITION                        | SYMBOL            | VALUE       | UNIT |  |
| Thermal resistance junction to ambient air  | On PC board<br>50 mm x 50 mm x 1.6 mm | R <sub>thJA</sub> | 500         | K/W  |  |
| Junction temperature  |                                       | Tj                | 175         | °C   |  |
| Storage temperature range   |                                       | T <sub>stg</sub>  | -65 to +175 | °C   |  |

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For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

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| ELECTRICAL CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified) |   |                   |      |      |      |      |
|---|---|-------------------|------|------|------|------|
| PARAMETER   | TEST CONDITION  | SYMBOL            | MIN. | TYP. | MAX. | UNIT |
| Forward voltage   | I <sub>F</sub> = 30 mA  | V <sub>F</sub>    |      |      | 1    | V    |
| Reverse current   | V <sub>R</sub> = 25 V   | I <sub>R</sub>    |      |      | 100  | nA   |
| nevelse current   | V <sub>R</sub> = 25 V, T <sub>j</sub> = 150 °C  | I <sub>R</sub>    |      |      | 100  | μA   |
| Breakdown voltage   | $I_{\rm R} = 5 \ \mu {\rm A}, \ t_{\rm p} / {\rm T} = 0.01, \ t_{\rm p} = 0.3 \ {\rm ms}$ | V <sub>(BR)</sub> | 35   |      |      | V    |
| Diode capacitance   | V <sub>R</sub> = 0, f = 1 MHz,<br>V <sub>HF</sub> = 50 mV                                 | CD                |      |      | 4    | pF   |
| Poveroo rocovery timo   | I <sub>F</sub> = I <sub>R</sub> = 10 mA,<br>i <sub>R</sub> = 1 mA                         | t <sub>rr</sub>   |      |      | 4    | ns   |
| Reverse recovery time   | $I_F = 10 \text{ mA}, V_R = 6 \text{ V}, \\ i_R = 0.1 \text{ x } I_R, R_L = 100 \Omega$   | t <sub>rr</sub>   |      |      | 2    | ns   |

#### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

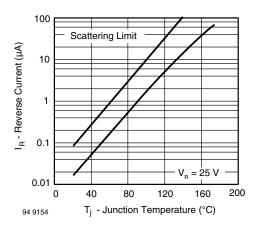


Fig. 1 - Reverse Current vs. Junction Temperature

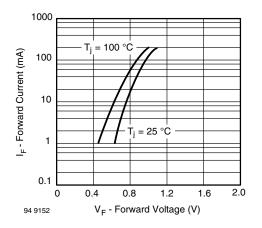


Fig. 2 - Forward Current vs. Forward Voltage

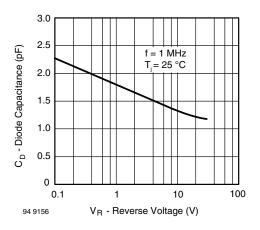


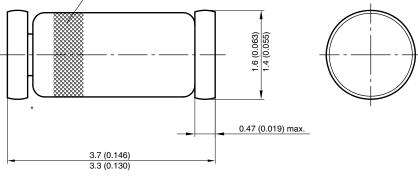
Fig. 3 - Diode Capacitance vs. Reverse Voltage

2

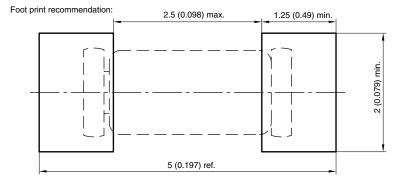


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## PACKAGE DIMENSIONS in millimeters (inches): MiniMELF (SOD-80)



\* The gap between plug and glass can be either on cathode or anode side



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